# Anisotropy of Resonant Inelastic X-Ray Scattering at the K Edge of Si:

Yunori NISIKAWA<sup>1\*</sup>, Manabu USUDA<sup>1</sup> and Jun-ichi IGARASHI<sup>2</sup>

**Theoretical Analysis** 

<sup>1</sup>Synchrotron Radiation Research Center, Japan Atomic Energy Research Institute, Mikazuki, Sayo, Hyogo 679-5148 <sup>2</sup>Faculty of Science, Ibaraki University, Mito, Ibaraki 310-8512

(Received December 30, 2021)

We investigate theoretically the resonant inelastic x-ray scattering (RIXS) at the K edge of Si on the basis of an ab initio calculation. We calculate the RIXS spectra with systematically varying transfered-momenta, incident-photon energy and incident-photon polarization. We confirm the anisotropy of the experimental spectra by Y. Ma *et al.* (Phys. Rev. Lett. 74, 478 (1995)), providing a quantitative explanation of the spectra.

KEYWORDS: resonant inelastic X-ray scattering, K edge of Si

### 1. Introduction

Inelastic x-ray scattering is a promising method to study electronic structures in matters. It is advantageous to use a resonant enhancement by tuning photon energy near absorption edge. Recently it has been revealed that the resonant inelastic x-ray scattering (RIXS) is a powerful tool for elucidating the electronic properties of solids. RIXS measurement has been applied to search for charge excitations in several cuprates<sup>1,2</sup> and manganites,<sup>3</sup> with tuning incident photon energy to the absorption K edge. Since corresponding photon energies are in the hard-X-ray region, the momentum transfer can not be neglected. Analyzing the transfered-momentum dependence of the RIXS spectra, we can clarify the characteristics of charge excitations in strongly-correlated electron systems.

In semiconductors such as Si and Ge, the interpretation of the RIXS spectra may be simpler because of weak electron correlations. The final state of RIXS consists of one electron in the conduction band and one hole in the valence band. With neglecting the interaction between the electron and the hole, one can draw useful information of single-particle spectra from the transferred-momentum dependence. Actually Ma has tried to determine valence band structures of Si by systematically varying scattering vectors in the RIXS experiment.<sup>4</sup>

We have already carried out a RIXS experiment at the K edge of Ge with the same aim. Although we systematically varied transfered-momenta, we obtained merely a broad inelastic peak as a function of photon energy, whose shape was nearly independent of transfered-

<sup>\*</sup>E-mail address:nisikawa@spring8.or.jp

momenta. Performing the band structure calculation, we obtain the spectral shape in agreement with the experiment, and clarified the origin of the spectral shape.<sup>5</sup> This analysis led us to realize that the decisive factor whether the spectra are depending on the transferred momenta or not is the core-level width. If the core-hole level in the intermediate state is sharp enough, we can definitely select the momentum of the excited electron in the conduction band by sharply tuning the incident-photon energy, and thereby we can also specify the momentum of the hole in the valence band by setting the scattering geometry. In this situation, sharp peaks are expected to be observed as a function of scattered photon energy. If the core-level width is not small, many channels of exciting an electron with different momenta in the conduction band are expected to be opened. Thereby, sharp peaks are blurred up by overlapping each contribution. In an extreme situation, the spectra become close to a superposition of the density of states (DOS) projected onto *p*-symmetric states. Unfortunately, for Ge, the 1*s* core-level width is as large as ~ 2eV, an order of the width of conduction band, so that the RIXS spectra did not show clear momentum dependence.

For Si, since the K edge energy is around 1840 eV, the transfered-momentum cannot be neglected in the RIXS experiment. The 1s core-level width is estimated about 0.6 eV, which is smaller than the width of conduction band of Si. These facts imply a possibility of observing the transfered-momentum dependence at the K edge in the RIXS spectra. Actually, Ma *et. al* observed such transfered-momentum dependence.<sup>6</sup> In this paper, we analyze Ma's experimental RIXS spectra with the help of *ab initio* band structure calculation, and elucidate the relation between the spectral shape and the underlying electronic structure.

This paper is organized as follows. In §2, the formalism for calculating the spectra is described. In §3, the calculated results and discussion are presented. Section 4 is devoted to concluding remarks.

## 2. Formulation

RIXS is described by a second-order process that the incident photon with energy  $\hbar\omega_1$ , momentum  $\hbar \mathbf{q}_1$  and polarization  $\mathbf{e}_1$  is virtually absorbed by exciting the core electron to the conduction band and then a photon with energy  $\hbar\omega_2$ , momentum  $\hbar \mathbf{q}_2$  and polarization  $\mathbf{e}_2$ is emitted by filling the core-hole state with a valence electron. The scattering geometry is shown in Fig. 1. The normal axis  $\mathbf{n}$  and theta axis  $\mathbf{t}$  in this figure are respectively defined as follows:  $\mathbf{n} \propto \mathbf{q}_2/|\mathbf{q}_2| - \mathbf{q}_1/|\mathbf{q}_1|$ ,  $\mathbf{t} \propto \mathbf{q}_1 \times \mathbf{q}_2$ . The setup for scattering is uniquely determined by choosing the normal and theta axis from crystal axes of Si.

To obtain the double differential scattering cross-section, we use the generalized Fermi's golden rule where the interaction between photon and electrons is treated by second order perturbation theory. An independent-particle approximation seems to be appropriate, since electron correlations are expected to be weak.<sup>4</sup> In such a situation, the double differential

scattering cross-section may be expressed as

$$\frac{d^2\sigma}{d\omega_2 d\Omega_2} \propto \sum_{(\mathbf{k},e),(\mathbf{k}',h)} \frac{\left|\sum_a \exp(i\mathbf{\Omega} \cdot \mathbf{R}_a) \overline{t_a(\mathbf{k}',h|\mathbf{e}_2)} t_a(\mathbf{k},e|\mathbf{e}_1)\right|^2}{(\epsilon_e(\mathbf{k}) - \epsilon_c - \hbar\omega_1)^2 + \Gamma^2/4} \delta^{\mathbf{G}}_{\mathbf{\Omega},\mathbf{k}-\mathbf{k}'} \delta(\epsilon_e(\mathbf{k}) - \epsilon_h(\mathbf{k}') - \hbar\omega),$$
(1)

where  $\hbar\omega = \hbar\omega_1 - \hbar\omega_2$ , and  $\hbar\Omega = \hbar\mathbf{q}_1 - \hbar\mathbf{q}_2$  are energy and momentum of the final state.  $\epsilon_e(\mathbf{k}), \epsilon_h(\mathbf{k}')$  and  $\epsilon_c$  are the energy of the excited electron with crystal momentum  $\mathbf{k}$  in the conduction band e, that of the hole with crystal momentum  $\mathbf{k}'$  in the valence band h, and that of the core state, respectively. Overlined quantity indicates the complex conjugate. The  $\Gamma$  is the 1s core-level width of Si. Quantity  $t_a(\mathbf{k}', h|\mathbf{e}_2) \equiv \int d\mathbf{r} \overline{\psi_{\mathbf{k}',h}(\mathbf{r})} \mathbf{e}_2 \cdot \hat{\mathbf{p}} \phi_a^{1s}(\mathbf{r} - \mathbf{R}_a)$  describes the transition from the valence band to the 1s core state, where  $\mathbf{R}_a, \psi_{\mathbf{k}',h}$  and  $\phi_a^{1s}$  are the position vector of atom a in unit cell, Bloch-wave function of an electron in the valence band h with crystal momentum  $\mathbf{k}'$ , and 1s-atomic orbital, respectively. The crystal momentum conservation for the whole process is contained in the factor of Kronecker  $\delta$ ,

$$\delta_{\mathbf{\Omega},\mathbf{k}-\mathbf{k}'}^{\mathbf{G}} \equiv \begin{cases} 0 & : \mathbf{\Omega} - (\mathbf{k} - \mathbf{k}') \notin \mathbf{G} \\ 1 & : \mathbf{\Omega} - (\mathbf{k} - \mathbf{k}') \in \mathbf{G} \end{cases},$$
(2)

where  $\mathbf{G}$  is the set of reciprocal lattice vectors.

## 3. Calculated Results and Discussion

### 3.1 Band Structure Calculation of Si

We perform a band structure calculation using the full-potential linearized augmentedplane-wave (FLAPW) method within the local-density approximation (LDA). The local exchange-correlation functional of Vosko, Wilk and Nusair is employed.<sup>7</sup> The angular momentum in the spherical-wave expansion is truncated at  $l_{\text{max}} = 6$  and 7 for the potential and wave function, respectively. The energy cutoff of the plane wave is 12 Ry for the wave function. Figure 2 shows the energy vs. momentum relation thus evaluated. The energy band is labeled by attached numbers for later use.

## 3.2 RIXS spectra

## 3.2.1 Anisotropy of RIXS at K edge of Si

We first analyze the transfered-momentum dependence of RIXS spectra for the incident photon energy  $\hbar\omega_1 = \epsilon_{\min} - \epsilon_c$ , where  $\epsilon_{\min}$  is the minimum energy of conduction-bands. When  $\Gamma$  is very small, the denominator in Eq. 1 forces the excited electron stay just at the bottom of the conduction band. There are six such points, which are denoted as  $\mathbf{k}_i$  ( $i = 1, \dots, 6$ ) in Fig. 3. They belong to band 5 (see Fig.2). We can specify the momentum of hole  $\mathbf{q}_i \equiv \mathbf{k}_i - \mathbf{\Omega}$  in the valence band by specifying the scattering vector. In such a situation, the double differential

Full Paper

scattering cross-section can be rewritten as

$$\frac{d^2\sigma}{d\omega_2 d\Omega_2} \propto \sum_{i,h} A(i,h|\mathbf{\Omega},\mathbf{e}_1)\delta(\epsilon_{\min}-\epsilon_h(\mathbf{q}_i)-\hbar\omega), \qquad (3)$$

$$A(i,h|\mathbf{\Omega},\mathbf{e}_1) \equiv \sum_{\mathbf{e}_2} \left| \sum_{a} e^{i\mathbf{\Omega}\cdot\mathbf{R}_a} \overline{t_a(\mathbf{q}_i,h|\mathbf{e}_2)} t_a(\mathbf{k}_i,5|\mathbf{e}_1) \right|^2.$$
(4)

The sharp peaks are expected at  $\hbar \omega = \hbar \omega(i, h) \equiv \epsilon_{\min} - \epsilon_h(\mathbf{q}_i)$  in the spectra, where h  $(= 1, \dots, 4)$  indicates the valence band index. When the scattering vector is along a symmetry line, the number of peaks is reduced because of degeneracy of peaks and no intensities to some peaks. For  $\mathbf{n} = (100)$ , for example, the momenta of the holes are shown in Fig.3, and the corresponding valence band energies are the same due to symmetry, that is,  $\epsilon_h(\mathbf{q}_2) = \epsilon_h(\mathbf{q}_3) = \epsilon_h(\mathbf{q}_4) = \epsilon_h(\mathbf{q}_5)$  with  $h = 1, \dots, 4$ , except for  $\mathbf{q}_1$  and  $\mathbf{q}_6$ . Therefore, several excitation energies coincide with each other, and thereby different peak positions are  $\hbar \omega = \hbar \omega(1, h), \hbar \omega(2, h), \hbar \omega(6, h)$  with  $h = 1, \dots, 4$ . In addition, the spectral weights  $A(i, h | \mathbf{\Omega}, \mathbf{e}_1 = \sigma)$  for momentum  $\mathbf{k}_1$  and  $\mathbf{k}_6$  are found to be almost zero. Thus only four peaks appear at  $\hbar \omega = \hbar \omega(2, h)(h = 1, \dots, 4)$ , as shown in Fig. 4 (c). With slight increase of the  $\Gamma$  value, the excited electron can stay at several states near the bottom of the conduction band, and thereby the valence hole can stay at several states near  $\mathbf{q}_i(i = 2, \dots, 5)$ . Therefore the spectral peaks are obscured. We can make similar analysis for  $\mathbf{n} = (111), (110)$ . Such spectral changes are demonstrated in Fig.4 for  $\mathbf{n} = (111), (110)$  and (100), with  $\Gamma$  changed from 0.02 eV to 0.6 eV.

When  $\Gamma$  is large, the momentum of the excited electron can take whole values in the first Brillouin zone, and so does the momentum of the hole in the valence band. The spectral peaks are smeared out, and thereby becoming close to the DOS projected onto p symmetric states. Thus we have the spectra almost independent of scattering vector. This behavior is demonstrated in Fig.5, where  $\Gamma = 1.6$  eV.

For the actual Si case,  $\Gamma$  is close to 0.6 eV, and the spectral shape is expected to show the transferred-momentum dependence. Figure 6 shows the RIXS spectra with  $\Gamma = 0.6$  eV for  $\hbar\omega_1 = 1840.8$  eV, in comparison with experimental results by Ma *et. al.*<sup>6</sup> In the experimental setup of Ma *et. al*,<sup>6</sup> the normal axis **n** is (111), (110), and (100), but the theta axis **t** and incident-photon polarization are not clearly indicated in their paper.<sup>6</sup> Assuming the  $\sigma$ polarization for the incident photon and the theta axis **t** as given in the figure, we are successful in reproducing the experimental shape such as three peak structure for **n** = (111) and the different spectral shape for **n** = (110) and (100). Corresponding to the above discussion, we can identify where the peak structures come from by decomposing the spectra into each contribution from the hole band and the electron band. Figure 7 shows such decomposition, where attached numbers indicates the band index given in Fig. 2.

# 3.2.2 Incident-photon energy dependence of RIXS spectra

The spectra strongly depend on the incident-photon energy. Figure 8 shows the spectra with varying incident-photon energy from 1840.0 eV to 1841.2 eV. The scattering vector is fixed to be proportional to  $\mathbf{n} = (111)$ . The characteristic three peaks A, B and C are visible only in the narrow energy region between 1840.2 eV and 1840.8 eV. For  $\hbar\omega_1 = 1842.5$  eV, the anisotropy almost disappears, as shown in Fig. 9. The result is consistent with experimental results of Ma *et. al.*<sup>6</sup>

## 3.2.3 Incident-photon polarization dependence

Figure 10 shows the RIXS spectra calculated for  $\sigma$  and  $\pi$  incident polarizations. It is found that the difference in RIXS spectra in higher  $\hbar\omega_2$  for  $\mathbf{n} = (100)$  is large, while not for  $\mathbf{n} = (111)$  and (110). This tendency is more clearly seen in the limit situation  $\Gamma = 0.02$ eV where  $\hbar\omega_1 = \epsilon_{\min} - \epsilon_c$ , as shown in Fig.11. The positions of peaks expected to be made by each electron-hole pairs are also presented in Fig.11. To make the discussion clear, we consider the limit situation mentioned above. Then, the 1s electron is excited to the states with momentum  $\mathbf{k}_i$   $(i = 1, \dots, 6)$ . Corresponding wave functions projected onto p-symmetric states centering on  $\mathbf{R}_a(a=1,2)$  are given by  $P_{l=1}\psi_{\mathbf{k}_1,5} \propto p_x$ ,  $P_{l=1}\psi_{\mathbf{k}_2,5} \propto p_y$ ,  $P_{l=1}\psi_{\mathbf{k}_3,5} \propto p_y$ ,  $P_{l=1}\psi_{\mathbf{k}_4,5} \propto p_z$ ,  $P_{l=1}\psi_{\mathbf{k}_5,5} \propto p_z$ ,  $P_{l=1}\psi_{\mathbf{k}_6,5} \propto p_x$ , as shown in the left side of Fig.11. In the case of  $\mathbf{n} = (100), \mathbf{t} = (011)$ , the incident-photon polarization vector  $\mathbf{e}_1$  is proportional to (0,1,1) in the  $\sigma$  polarization and  $(\sqrt{2},-1,1)$  in the  $\pi$  polarization. The x-component of  $\mathbf{e}_1$  is not zero only in the case of  $\pi$  polarization. Then the  $t_a(\mathbf{k}_i, 5|\mathbf{e}_1)$  in Eq.4 shows a large change at  $\mathbf{k}_1$  and  $\mathbf{k}_6$ , with changing polarization;  $|t_a(\mathbf{k}_{1,6}, 5|\pi)| >> |t_a(\mathbf{k}_{1,6}, 5|\sigma)| \simeq 0$ ,  $|t_a(\mathbf{k}_{2,\dots,5},5|\pi)| \simeq |t_a(\mathbf{k}_{2,\dots,5},5|\sigma)|$ . Therefore, we can expect that the electron-hole pairs with momenta  $\mathbf{k}_1$ ,  $\mathbf{q}_1$  and  $\mathbf{k}_6$ ,  $\mathbf{q}_6$  contribute to RIXS spectrum in the case of the  $\pi$  polarization. Note that the positions of the peaks made by the electron-hole pairs with momenta  $\mathbf{k}_1, \mathbf{q}_1$ and  $\mathbf{k}_6$ ,  $\mathbf{q}_6$  in the  $\pi$  polarization are quite different from these of the peaks made by other electron-hole pairs with momenta  $\mathbf{k}_i$ ,  $\mathbf{q}_i$  ( $i = 2, \dots, 5$ ). From Fig. 11(c), we find that electronhole pairs with momenta  $\mathbf{k}_1$ ,  $\mathbf{q}_1$  for h = 2, 3, 4, and  $\mathbf{k}_6$ ,  $\mathbf{q}_6$  for h = 3, 4 significantly contribute to forming the peak around  $\hbar\omega_2 = 1839$  eV in the  $\pi$  polarization. Such a contribution gives rise to the appreciable intensity around  $\hbar\omega_2 = 1839$  eV in the realistic RIXS spectrum for the  $\pi$  polarization, as shown in Fig. 10. The same discussion mentioned above can be applied in the case of  $\mathbf{n} = (111)$ ,  $\mathbf{t} = (1-10)$  and  $\mathbf{n} = (110)$ ,  $\mathbf{t} = (1-10)$ . In the case of  $\mathbf{n} = (111)$ ,  $\mathbf{t} = (1-10)$ 10) and  $\mathbf{n} = (110)$ ,  $\mathbf{t} = (1-10)$ , the incident-photon polarization vector  $\mathbf{e}_1$  is proportional to (1, -1, 0) in the  $\sigma$  polarization and  $(1, 1, \alpha), (\alpha \neq 0)$  in the  $\pi$  polarization. The z-component of  $\mathbf{e}_1$  is not zero only in the case of  $\pi$  polarization. Therefore, the  $t_a(\mathbf{k}_i, 5|\mathbf{e}_1)$  shows a large change at  $\mathbf{k}_4$  and  $\mathbf{k}_5$ , with changing the polarization;  $|t_a(\mathbf{k}_{4,5},5|\pi)| >> |t_a(\mathbf{k}_{4,5},5|\sigma)| \simeq 0$ ,  $|t_a(\mathbf{k}_{1,2,3,6},5|\pi)| \simeq |t_a(\mathbf{k}_{1,2,3,6},5|\sigma)|$ . Therefore, we can expect that the electron-hole pairs with momenta  $\mathbf{k}_4$ ,  $\mathbf{q}_4$  and  $\mathbf{k}_5$ ,  $\mathbf{q}_5$  contribute to RIXS spectrum in the case of the  $\pi$  polarization.

From Fig. 11(a),(b), we can see the following facts. In the case of  $\mathbf{n} = (111)$ ,  $\mathbf{t} = (1-10)$ , the positions of the peaks made by the electron-hole pairs with momenta  $\mathbf{k}_4$ ,  $\mathbf{q}_4$  and  $\mathbf{k}_5$ ,  $\mathbf{q}_5$  in the  $\pi$  polarization are same as these of the peaks made by other electron-hole pairs with momenta  $\mathbf{k}_i$ ,  $\mathbf{q}_i$  (i = 1, 2, 3, 6). In the case of  $\mathbf{n} = (110)$ ,  $\mathbf{t} = (1-10)$ , the position of the peak made by the electron-hole pairs with momenta  $\mathbf{k}_4$ ,  $\mathbf{q}_4$  and  $\mathbf{k}_5$ ,  $\mathbf{q}_5$  for h = 2 in the  $\pi$  polarization is same as that of the main peak in the  $\sigma$  polarization. On the other hand, the positions of the peaks made by the electron-hole pairs with momenta  $\mathbf{k}_4$ ,  $\mathbf{q}_4$  and  $\mathbf{k}_5$ ,  $\mathbf{q}_5$  for h = 3, 4 in the  $\pi$  polarization are different from that of the peaks made by other electron-hole pairs with momenta  $\mathbf{k}_4$ ,  $\mathbf{q}_4$  and  $\mathbf{k}_5$ ,  $\mathbf{q}_5$  for h = 3, 4 in the momenta  $\mathbf{k}_i$ ,  $\mathbf{q}_i$  (i = 1, 2, 3, 6). But the new peaks made by electron-hole pairs with momenta  $\mathbf{k}_4$ ,  $\mathbf{q}_4$  and  $\mathbf{k}_5$ ,  $\mathbf{q}_5$  for h = 3, 4 are not so significant. Summarizing, in the case of  $\mathbf{n} = (111)$ ,  $\mathbf{t} = (1-10)$  and  $\mathbf{n} = (110)$ ,  $\mathbf{t} = (1-10)$ , significant peaks at new positions are not expected by varying incident-photon polarization. Therefore, the realistic RIXS spectra for  $\mathbf{n} = (111)$ ,  $\mathbf{t} = (1-10)$  and  $\mathbf{n} = (110)$ ,  $\mathbf{t} = (1-10)$  are not sensitive to the incident-photon polarization, as shown in Fig. 10.

## 4. Concluding Remarks

We have calculated the RIXS spectra at the K edge of Si on the basis of the band structure calculation. We have successfully reproduced the anisotropy of the RIXS spectra in the experiment by Ma *et. al.*<sup>6</sup> We have analyzed the spectra with systematically varying transfered-momenta, incident-photon energy and incident-photon polarization, thus having provided a quantitative explanation of the spectra. With the help of the band calculation, one can draw information on the valence band structure from the RIXS spectra, although it is indirect. This information seems helpful with considering that the RIXS is bulk-sensitive in contrast to photoemission with a lower energy photon which is surface-sensitive.

Finally, we comment the following general tendencies. To have an anisotropy in RIXS at K edge of specific element in semiconductor or band-insulator, the sizable momentum transfer and core-level width smaller than conduction-bandwidth are required. The photon energy is required to obtain sizable momentum transfer but corresponding core-level widths are usually large. Therefore, it is difficult to satisfy the requirement of the sizable momentum transfer and small core-level width.

## Acknowledgment

Authors greatly thank to N. Hamada for allowing us to use his FLAPW code, and to T. Iwazumi and A. Agui for valuable discussion. This work was supported in part by a Grantin-Aid for Scientific Research from the Ministry of Educations, Science, Sports, and Culture. J. Phys. Soc. Jpn.

# References

- M. Z. Hasan, E. D. Isaacs, Z.-X. Shen, L. L. Miller, K. Tsutsui, T. Tohyama, and S. Maekawa, Science 288 (2000) 1811.
- 2) Y. J. Kim, J. P. Hill, C. A. Burns, S. Wakimoto, R. J. Birgeneau, D. Casa, T. Gog, and C. T. Venkataraman, Phys. Rev. Lett. 89 (2002), 177003.
- 3) T. Inami, T. Fukuda, J. Mizuki, S. Ishihara, H. Kondo, H. Nakao, T. Matsumura, K. Hirota, Y. Murakami, S. Maekawa, and Y. Endoh, Phys. Rev. B 67 (2003) 045108.
- 4) Y. Ma, Phys. Rev. B 49 (1994) 5799.
- 5) Y. Nisikawa, M. Usuda, J. Igarashi, H. Shoji, and T. Iwazumi, J. Phys. Soc. Jpn. 73 (2004) 970.
- 6) Y. Ma, K. E. Miyano, P. L. Cowan, Y. Aglitzkiy, and B. A. Karlin, Phys. Rev. Lett. 74 (1995) 478.
- 7) S. H. Vosko, L. Wilk and M. Nusair, Can. J. Phys. 58 (1980) 1200.
- 8) J. H. Scofield, Phys. Rev. 179 (1969) 9.
- 9) V. O. Kostroun, M. H. Chen, and B. Crasemann, Phys. Rev. A 3 (1971) 533.

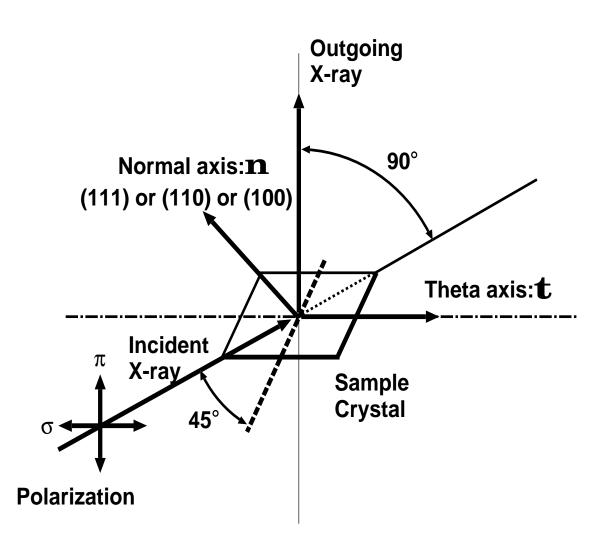


Fig. 1. Geometrical relations between  $\mathbf{q}_1, \mathbf{q}_2$  and crystal axis of Si.

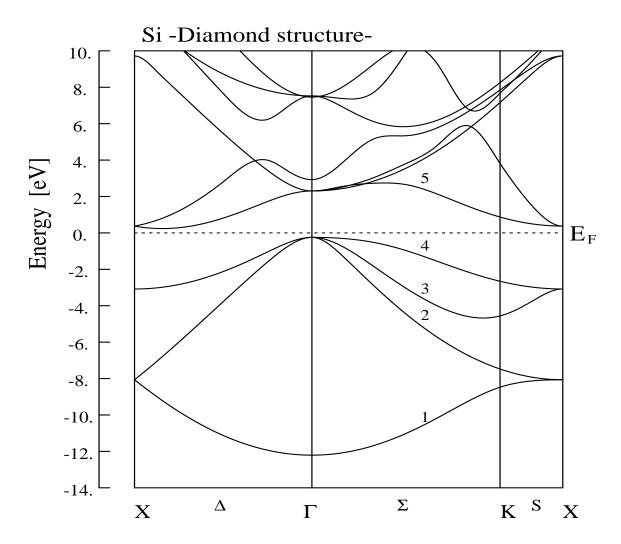


Fig. 2. Energy vs. momentum relation of Si calculated by the FLAPW method in the LDA scheme.

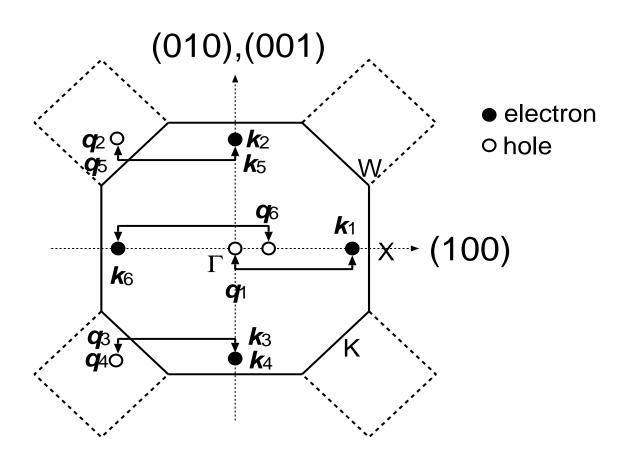
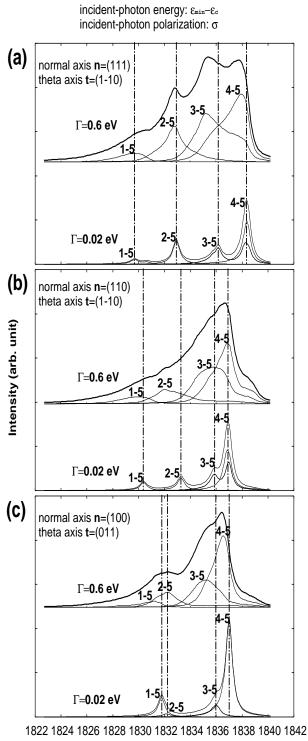


Fig. 3. Cross-section of the first Brillouin zone. The crystal momenta of electrons and holes generated in final state are presented.



Emitted Photon Energy (eV)

Fig. 4. RIXS spectra for realistic value of core-level width ( $\Gamma = 0.6 \text{ eV}$ ) in comparison with the RIXS spectra for sufficiently small value of core-level width ( $\Gamma = 0.02 \text{ eV}$ ).

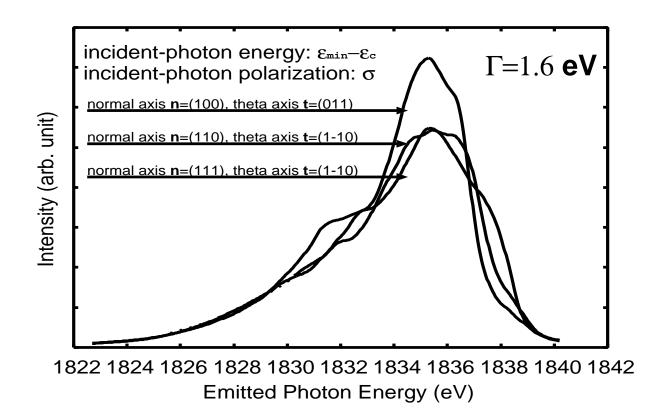


Fig. 5. RIXS spectra for large value of core-level width ( $\Gamma = 1.6 \text{ eV}$ ). The anisotropy almost disappears in the spectra.

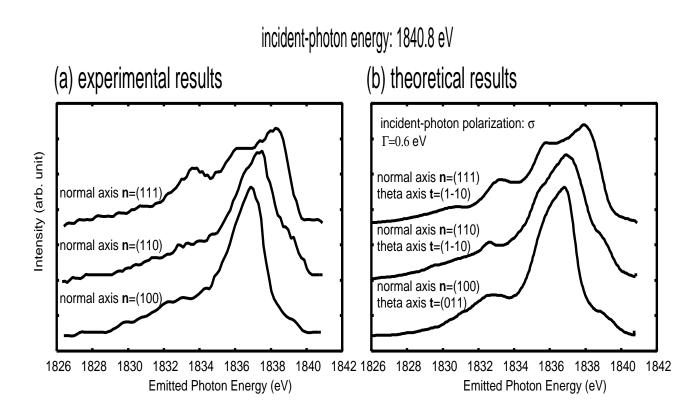
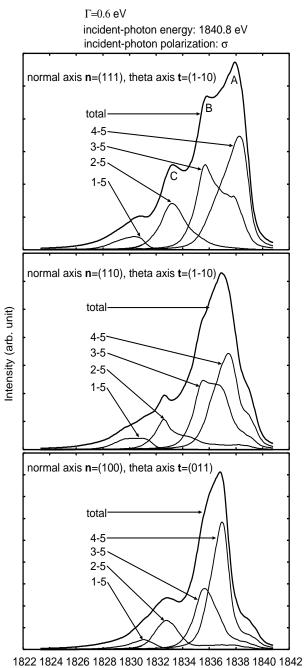


Fig. 6. RIXS spectra obtained by (a)experiment<sup>6</sup> and (b)theory



Emitted Photon Energy (eV)

Fig. 7. The spectra for  $\hbar\omega_1 = 1840.8 \text{ eV}$ ,  $\mathbf{n} = (111)$ , (110), and (100) are decomposed into each contribution of band-to-band transitions specified by band indices.

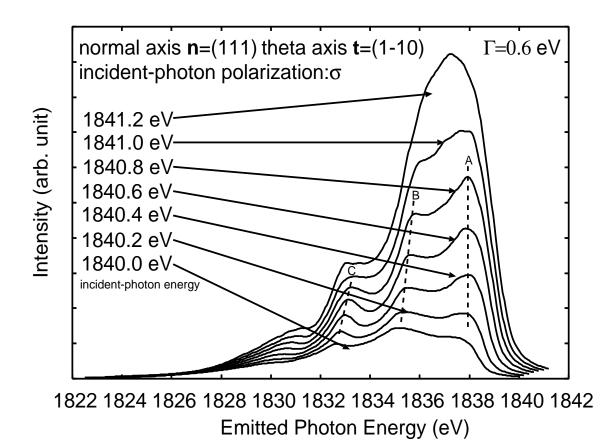


Fig. 8. Calculated RIXS spectra for n=(111) with varying incident-photon energy between 1840.0 eV and 1841.2 eV.

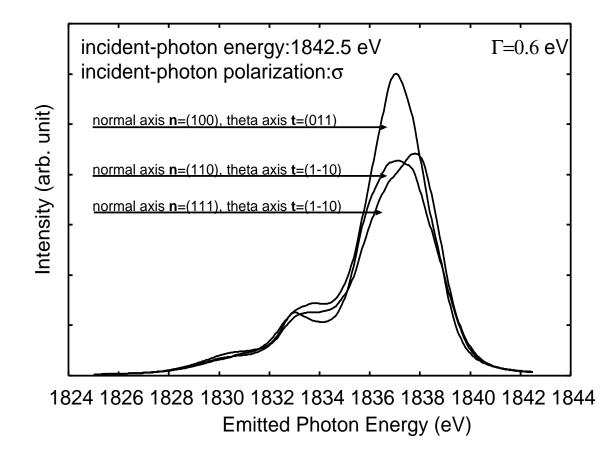


Fig. 9. Calculated RIXS spectra for  $\hbar\omega_1 = 1842.5$  eV with varying  $\mathbf{n} = (111)$ , (110), and (100).

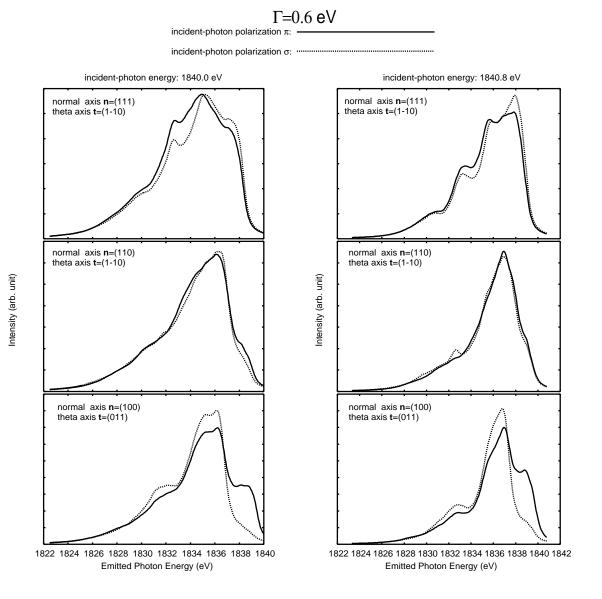


Fig. 10. Calculated RIXS spectra with varying incident-photon polarization.

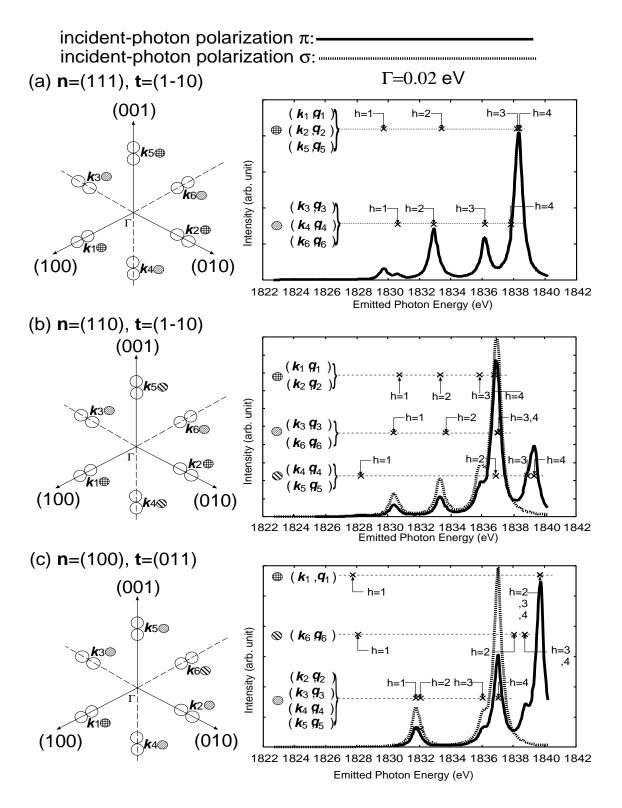


Fig. 11. Incident-photon polarization dependence of RIXS spectra for  $\hbar\omega_1 = \epsilon_{\min} - \epsilon_c$  with sufficiently small value of  $\Gamma(=0.02 \text{ eV})$ . The positions of peaks expected to be made by each electron-hole pairs are also presented.